





TPS3808 SBVS050M - MAY 2004 - REVISED MARCH 2023

TPS3808 Low-Quiescent-Current, Programmable-Delay Supervisory Circuit

1 Features

- Power-on reset generator with adjustable delay time: 1.25 ms to 10 s
- Very low quiescent current: 2.4 µA typical
- High threshold accuracy: 0.5% typical
- Fixed threshold voltages for standard voltage rails from 0.9 V to 5 V and adjustable voltage down to 0.4 V are available
- Manual reset (MR) input
- Open-drain RESET output
- Temperature range: -40°C to 125°C
- Small SOT-23 and 2-mm × 2-mm WSON packages

2 Applications

- DSP or microcontroller applications
- Notebook and desktop computers
- PDAs and hand-held products
- Portable and battery-powered products
- FPGA and ASIC applications

3 Description

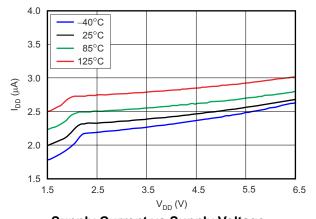
The TPS3808 family of microprocessor supervisory circuits monitors system voltages from 0.4 V to 5 V, asserting an open-drain RESET signal when the SENSE voltage drops below a preset threshold or when the manual reset (MR) pin drops to a logic low. The RESET output remains low for the user-adjustable delay time after the SENSE voltage and manual reset (\overline{MR}) return above the respective thresholds.

The TPS3808 device uses a precision reference to achieve 0.5% threshold accuracy for V_{IT} ≤ 3.3 V. The reset delay time can be set to 20 ms by disconnecting the C_T pin, 300 ms by connecting the C_T pin to V_{DD} using a resistor, or can be user-adjusted between 1.25 ms and 10 s by connecting the C_T pin to an external capacitor. The TPS3808 device has a very low typical quiescent current of 2.4 µA, so it is wellsuited to battery-powered applications. It is available in the SOT-23 and 2-mm × 2-mm WSON packages, and is fully specified over a temperature range of -40°C to 125°C (T_J).

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
TPS3808	SOT-23 (6)	2.90 mm x 1.60 mm
1253808	WSON (6)	2.00 mm x 2.00 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Supply Current vs Supply Voltage

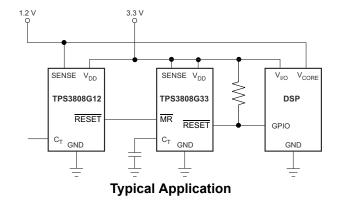




Table of Contents

1 Features	1	8.4 Device Functional Modes	13
2 Applications	1	9 Application and Implementation	14
3 Description	1	9.1 Application Information	14
4 Revision History	<mark>2</mark>	9.2 Typical Application	
5 Device Voltage Thresholds	3	10 Power Supply Recommendations	15
6 Pin Configuration and Functions	4	11 Layout	15
7 Specifications	<mark>5</mark>	11.1 Layout Guidelines	
7.1 Absolute Maximum Ratings		11.2 Layout Example	
7.2 ESD Ratings		12 Device and Documentation Support	
7.3 Recommended Operating Conditions	<mark>5</mark>	12.1 Device Support	
7.4 Thermal Information	<mark>5</mark>	12.2 Documentation Support	17
7.5 Electrical Characteristics	6	12.3 Support Resources	
7.6 Switching Characteristics	7	12.4 Trademarks	17
7.7 Typical Characteristics		12.5 Electrostatic Discharge Caution	17
8 Detailed Description		12.6 Glossary	17
8.1 Overview	10	13 Mechanical, Packaging, and Orderable	
8.2 Functional Block Diagram	10	Information	17
8.3 Feature Description	10		

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	hanges from Revision L (September 2020) to Revision M (March 2023)	Page
•	Updated Device Voltage Thresholds footnote	3
•	Updated Thermal Information	5
C	hanges from Revision K (October 2015) to Revision L (September 2020)	Page
•	Updated the numbering format for tables, figures and cross-references throughout the document	1
С	hanges from Revision J (August 2008) to Revision K (October 2015)	Page
•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and	
	Implementation section, Power Supply Recommendations section, Layout section, Device and	
	Documentation Support section, and Mechanical, Packaging, and Orderable Information section. Mov	ed
	Switching Characteristics table, timing diagram, and related truth table	1
•	Changed Figure 9-1; removed capacitor shown on C _T	14

Submit Document Feedback Product Folder Links: TPS3808



5 Device Voltage Thresholds

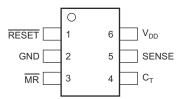
The following table shows the nominal rail to be monitored and the corresponding threshold voltage of the device.

PART NUMBER	NOMINAL SUPPLY VOLTAGE(1)	THRESHOLD VOLTAGE (V _{IT})
TPS3808G01	Adjustable	0.405 V
TPS3808G09	0.9 V	0.84 V
TPS3808G12	1.2 V	1.12 V
TPS3808G125	1.25 V	1.16 V
TPS3808G15	1.5 V	1.40 V
TPS3808G18	1.8 V	1.67 V
TPS3808G19	1.9 V	1.77 V
TPS3808G25	2.5 V	2.33 V
TPS3808G30	3 V	2.79 V
TPS3808G33	3.3 V	3.07 V
TPS3808G50	5 V	4.65 V

⁽¹⁾ Please contact TI for availability of other threshold options.



6 Pin Configuration and Functions



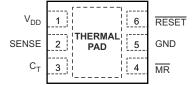


Figure 6-1. DBV Package 6-Pin SOT-23 Top View

Figure 6-2. DRV Package 6-Pin (2.00 mm × 2.00 mm) WSON With Thermal Pad Top View

Table 6-1. Pin Functions

	PIN		1/0	DECODINE	
NAME	SOT-23	WSON	I/O	DESCRIPTION	
Ст	4	3	I	Reset period programming pin. Connecting this pin to V_{DD} through a 40-k Ω to 200-k Ω resistor or leaving it open results in fixed delay times (see Section 7.5). Connecting this pin to a ground referenced capacitor \geq 100 pF gives a user-programmable delay time. See Section 8.3.2 for more information.	
GND	2	5	_	Ground	
MR	3	4	I	Driving the manual reset pin (\overline{MR}) low asserts \overline{RESET} . \overline{MR} is internally tied to V_{DD} by a 90-k Ω pull-up resistor.	
RESET	1	6	0	RESET is an open-drain output that is driven to a low-impedance state when RESET is asserted (either the SENSE input is lower than the threshold voltage (V _{IT}) or the $\overline{\text{MR}}$ pin is set to a logic low). RESET remains low (asserted) for the reset period after both SENSE is above V _{IT} and $\overline{\text{MR}}$ is set to a logic high. A pull-up resistor from 10 k Ω to 1 M Ω should be used on this pin, and allows the reset pin to attain voltages higher than V _{DD} .	
SENSE	5	2	I	This pin is connected to the voltage to be monitored. If the voltage at this terminal drops below the threshold voltage V_{IT} , then $\overline{\text{RESET}}$ is asserted.	
V _{DD}	6	1	ı	Supply voltage. It is good analog design practice to place a 0.1-µF ceramic capacitor close to this pin.	
Thermal Pad	_	Pad	_	Thermal Pad. Connect to ground plane to enhance thermal performance of package.	

Product Folder Links: TPS3808

7 Specifications

7.1 Absolute Maximum Ratings

over operating junction temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
	V_{DD}	-0.3	7	V
Voltage	V _{CT}	-0.3	V _{DD} + 0.3	V
	V _{RESET} , V _{MR} , V _{SENSE}	-0.3	7	V
Current	RESET pin	-5	5	mA
Tomporatura	Operating junction, T _J ⁽²⁾	-40	150	°C
Temperature	Storage, T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) As a result of the low dissipated power in this device, it is assumed that $T_J = T_A$.

7.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
V(ESD)	Liectrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{DD}	Input supply range	1.7		6.5	V
V _{SENSE}	SENSE pin voltage	0		6.5	V
V _(Ct)	C _T pin voltage			V_{DD}	V
V MR	MR pin voltage	0		6.5	V
V RESET	RESET pin voltage	0		6.5	V
I RESET	RESET pin current	0.0003		5	mA

7.4 Thermal Information

		TPS	TPS3808			
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	DRV (WSON)	UNIT		
		6 PINS	6 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	180.9	178.1	°C/W		
R _{0JC(top)}	Junction-to-case (top) thermal resistance	117.8	95.6	°C/W		
R _{0JB}	Junction-to-board thermal resistance	27.8	135	°C/W		
Ψлт	Junction-to-top characterization parameter	18.9	6.3	°C/W		
Ψ_{JB}	Junction-to-board characterization parameter	27.3	136.6	°C/W		
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	7.3	°C/W		

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

Copyright © 2023 Texas Instruments Incorporated

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics

 $1.7~V \le V_{DD} \le 6.5~V$, $R_{LRESET} = 100~k\Omega$, $C_{LRESET} = 50~pF$, over operating temperature range ($T_{J} = -40^{\circ}C$ to $125^{\circ}C$), unless otherwise noted. Typical values are at $T_{J} = 25^{\circ}C^{(1)}$.

	PARAMETI	ER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
.,	Innut oumply range		-40°C < T _J < 125°C	1.7		6.5	V	
V_{DD}	Input supply range		0°C < T _J < 85°C	1.65		6.5	V	
	Supply current (current into V _{DD} pin)		V _{DD} = 3.3 V, RESET not asserted MR, RESET, C _T open		2.4	5		
I _{DD}			V_{DD} = 6.5 V, RESET not asserted MR, RESET, C _T open		2.7	6	μA	
V	Low lovel output veltere		$1.3 \text{ V} \le \text{V}_{DD} < 1.8 \text{ V}, \text{I}_{OL} = 0.4 \text{ mA}$			0.3		
V _{OL}	Low-level output voltage		$1.8 \text{ V} \le \text{V}_{\text{DD}} \le 6.5 \text{ V}, \text{I}_{\text{OL}} = 1 \text{ mA}$			0.4	V	
V _{POR}	Power-up reset voltage ⁽²⁾		V _{OL} (max) = 0.2 V, I _{RESET} = 15 μA			0.8		
		TPS3808G01		-2%	±1%	2%		
		V _{IT} ≤ 3.3 V		-1.5%	±0.5%	1.5%		
V _{IT}	Negative-going input threshold accuracy	3.3 V < V _{IT} ≤ 5.0 V		-2%	±1%	2%		
		V _{IT} ≤ 3.3 V	-40°C < T _J < 85°C	-1.25%	±0.5%	1.25%		
		3.3 V < V _{IT} ≤ 5.0 V	-40°C < T _J < 85°C	-1.5%	±0.5%	1.5%		
.,	Hystorogic on V nin	TPS3808G01			1.5%	3%	V	
V _{HYS}	Hysteresis on V _{IT} pin	Fixed versions			1%	2.5%	V_{IT}	
R _{MR}	MR Internal pullup resis	stance		70	90		kΩ	
	Input current at	TPS3808G01	V _{SENSE} = V _{IT}	-25		25	nA	
ISENSE	SENSE pin	Fixed versions	V _{SENSE} = 6.5 V		1.7		μA	
I _{OH}	RESET leakage curren	t	V _{RESET} = 6.5 V, RESET not asserted			300	nA	
_	Input capacitance, any	C _T pin	V _{IN} = 0 V to V _{DD}		5		"F	
C _{IN}	pin	Other pins	V _{IN} = 0 V to 6.5 V		5		pF	
V _{IL}	MR logic low input			0		0.3 V _{DD}	V	
V _{IH}	MR logic high input			0.7 V _{DD}		V_{DD}	V	

Product Folder Links: TPS3808

Submit Document Feedback

The lowest supply voltage (V_{DD}) at which \overline{RESET} becomes active. $T_{rise(VDD)} \ge 15 \ \mu s/V$. R_{LRESET} and C_{LRESET} are the resistor and capacitor connected to the RESET pin.

7.6 Switching Characteristics

 $1.7~V \le V_{DD} \le 6.5~V$, $R_{LRESET} = 100~k\Omega$, $C_{LRESET} = 50~pF$, over operating temperature range ($T_{J} = -40^{\circ}C$ to $125^{\circ}C$), unless otherwise noted. Typical values are at $T_{J} = 25^{\circ}C$. (1)

	PARAMETE	iR .	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Input pulse width to	SENSE	V _{IH} = 1.05 V _{IT} , V _{IL} = 0.95 V _{IT}		20		
I _W	RESET	MR	$V_{IH} = 0.7 V_{DD}, V_{IL} = 0.3 V_{DD}$		0.001		μs
		C _T = Open		12	20	28	
	t _d RESET delay time	$C_T = V_{DD}$	See Figure 7-1	180	300	420	ms
t _d	NEOLT delay line	C _T = 100 pF		0.75	1.25	1.75	
		C _T = 180 nF		0.7	1.2	1.7	s
	Propagation delay	MR to RESET	$V_{IH} = 0.7 V_{DD}, V_{IL} = 0.3 V_{DD}$		150		ns
	High-to-low level RESET delay	SENSE to RESET	V _{IH} = 1.05 V _{IT} , V _{IL} = 0.95 V _{IT}		20		μs

(1) R_{LRESET} and C_{LRESET} are the resistor and capacitor connected to the RESET pin.

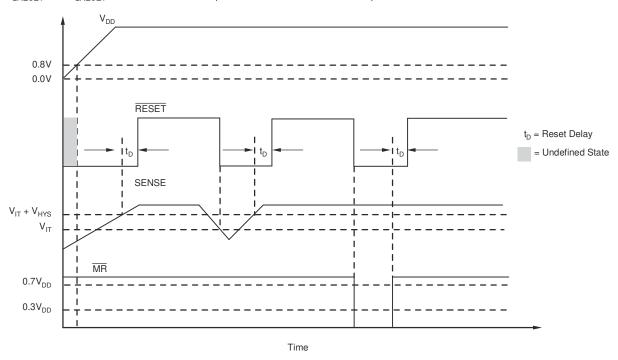
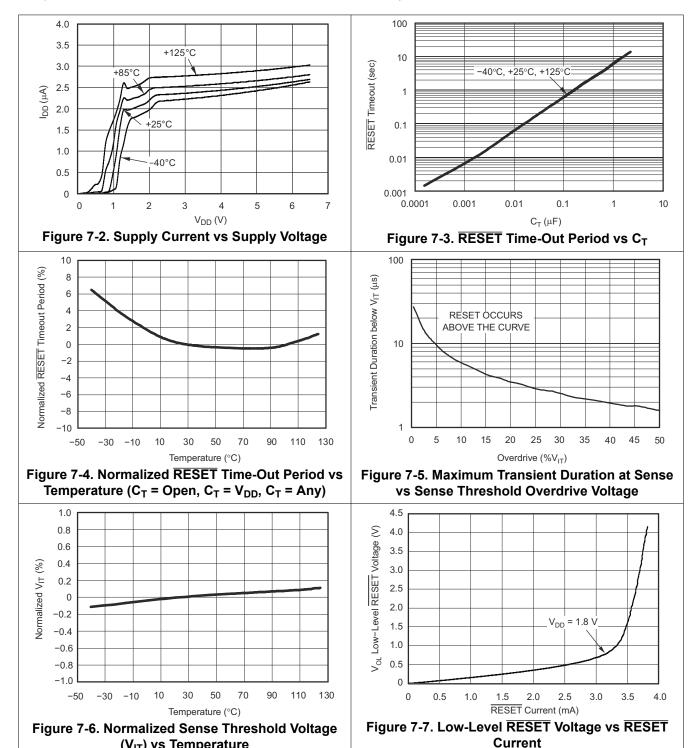


Figure 7-1. TPS3808 Timing Diagram Showing MR and SENSE Reset Timing



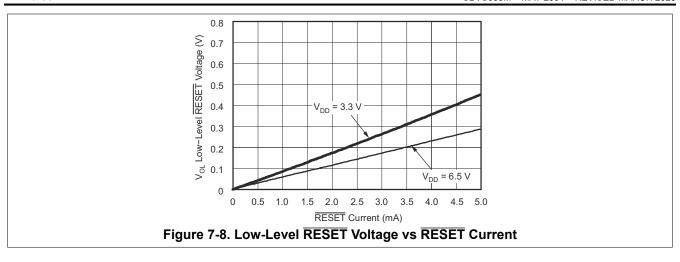
7.7 Typical Characteristics

At T_J = 25°C, V_{DD} = 3.3 V, R_{LRESET} = 100 k Ω , and C_{LRESET} = 50 pF, unless otherwise noted.



(V_{IT}) vs Temperature





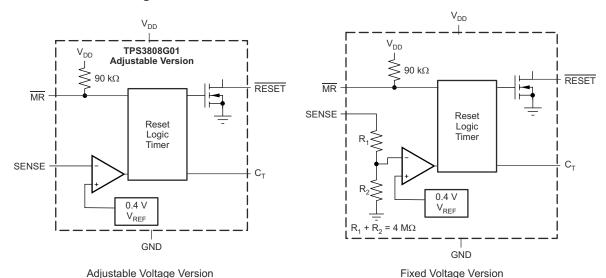


8 Detailed Description

8.1 Overview

The TPS3808 microprocessor supervisory product family is designed to assert a \overline{RESET} signal when either the SENSE pin voltage drops below V_{IT} or the manual reset (\overline{MR}) is driven low. The \overline{RESET} output remains asserted for a user-adjustable time after both the manual reset (\overline{MR}) and SENSE voltages return above their respective thresholds.

8.2 Functional Block Diagram



8.3 Feature Description

A broad range of voltage threshold and reset delay time adjustments are available for the TPS3808 device, allowing these devices to be used in a wide array of applications. Reset threshold voltages can be factory-set from 0.82 V to 3.3 V or from 4.4 V to 5 V, while the TPS3808G01 can be set to any voltage above 0.405 V using an external resistor divider. Two preset delay times are also user-selectable: connecting the C_T pin to V_{DD} results in a 300-ms reset delay, whereas leaving the C_T pin open yields a 20-ms reset delay. In addition, connecting a capacitor between C_T and GND allows the designer to select any reset delay period from 1.25 ms to 10 s.

8.3.1 SENSE Input

The SENSE input provides a pin at which any system voltage can be monitored. If the voltage on this pin drops below V_{IT} , then \overline{RESET} is asserted. The comparator has a built-in hysteresis to ensure smooth \overline{RESET} assertions and de-assertions. It is good analog design practice to put a 1-nF to 10-nF bypass capacitor on the SENSE input to reduce sensitivity to transients and layout parasitics.

The TPS3808 device is relatively immune to short negative transients on the SENSE pin. Sensitivity to transients is dependent on threshold overdrive, as shown in (Figure 7-5).

The TPS3808G01 can be used to monitor any voltage rail down to 0.405 V using the circuit shown in Figure 8-1.

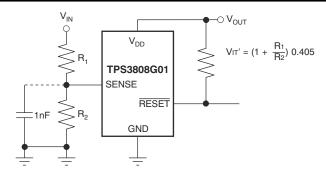


Figure 8-1. Using the TPS3808G01 to Monitor a User-Defined Threshold Voltage

8.3.2 Selecting the RESET Delay Time

The TPS3808 has three options for setting the \overline{RESET} delay time as shown in Figure 8-2. Figure 8-2 (a) shows the configuration for a fixed 300-ms typical delay time by tying C_T to V_{DD} ; a resistor from 40 k Ω to 200 k Ω must be used. Supply current is not affected by the choice of resistor. Figure 8-2 (b) shows a fixed 20-ms delay time by leaving the C_T pin open. Figure 8-2 (c) shows a ground referenced capacitor connected to C_T for a user-defined program time between 1.25 ms and 10 s.

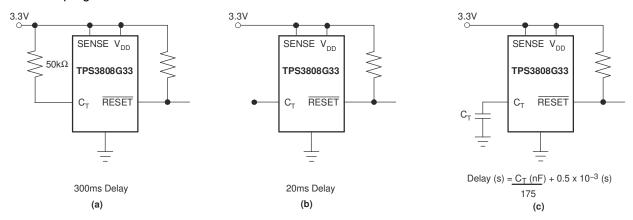


Figure 8-2. Configuration Used to Set the RESET Delay Time

The capacitor C_T should be \geq 100 pF nominal value in order for the TPS3808xxx to recognize that the capacitor is present. The capacitor value for a given delay time can be calculated using Equation 1.

$$C_T (nF) = [t_D (s) - 0.5 \times 10^{-3} (s)] \times 175$$
 (1)

The reset delay time is determined by the time it takes an on-chip precision 220-nA current source to charge the external capacitor to 1.23 V. When a RESET is asserted, the capacitor is discharged. When the RESET conditions are cleared, the internal current source is enabled and begins to charge the external capacitor. When the voltage on this capacitor reaches 1.23 V, RESET is deasserted. Note that a low-leakage type capacitor such as a ceramic should be used, and that stray capacitance around this pin may cause errors in the reset delay time.

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

8.3.3 Manual RESET (MR) Input

The manual reset ($\overline{\text{MR}}$) input allows a processor or other logic circuits to initiate a reset. A logic low (0.3 V_{DD}) on $\overline{\text{MR}}$ causes $\overline{\text{RESET}}$ to assert. After $\overline{\text{MR}}$ returns to a logic high and SENSE is above its reset threshold, $\overline{\text{RESET}}$ is de-asserted after the user-defined reset delay expires. Note that $\overline{\text{MR}}$ is internally tied to V_{DD} using a 90-k Ω resistor, so this pin can be left unconnected if $\overline{\text{MR}}$ is not used.

See Figure 8-3 for how \overline{MR} can be used to monitor multiple system voltages. Note that if the logic signal driving \overline{MR} does not go fully to V_{DD} , there is some additional current draw into V_{DD} as a result of the internal pullup resistor on \overline{MR} . To minimize current draw, a logic-level FET can be used as illustrated in Figure 8-4.

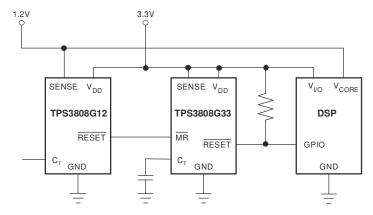


Figure 8-3. Using MR to Monitor Multiple System Voltages

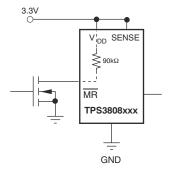


Figure 8-4. Using an External MOSFET to Minimize I_{DD} When MR Signal Does Not Go to V_{DD}

8.3.4 RESET Output

RESET remains high (unasserted) as long as SENSE is above its threshold (V_{IT}) and the manual reset (\overline{MR}) is logic high. If either SENSE falls below V_{IT} or \overline{MR} is driven low, \overline{RESET} is asserted, driving the \overline{RESET} pin to a low impedance.

Once $\overline{\text{MR}}$ is again logic high and SENSE is above $V_{\text{IT}} + V_{\text{HYS}}$ (the threshold hysteresis), a delay circuit is enabled that holds $\overline{\text{RESET}}$ low for a specified reset delay period. Once the reset delay has expired, the $\overline{\text{RESET}}$ pin goes to a high impedance state. The pullup resistor from the open-drain $\overline{\text{RESET}}$ to the supply line can be used to allow the reset signal for the microprocessor to have a voltage higher than V_{DD} (up to 6.5 V). The pullup resistor should be no smaller than 10 k Ω as a result of the finite impedance of the $\overline{\text{RESET}}$ line.

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated



8.4 Device Functional Modes

Table 8-1. Truth Table

MR	SENSE > V _{IT}	RESET
L	0	L
L	1	L
Н	0	L
Н	1	Н

8.4.1 Normal Operation (V_{DD} > V_{DD(min)})

When V_{DD} is greater than $V_{DD(min)}$, the \overline{RESET} signal is determined by the voltage on the SENSE pin and the logic state of \overline{MR} .

- MR high: When the voltage on V_{DD} is greater than 1.7 V for a time of the selected t_D, the RESET signal corresponds to the voltage on SENSE relative to V_{IT}.
- MR low: in this mode, RESET is held low regardless of the value of the SENSE pin.

8.4.2 Above Power-On Reset but Less Than $V_{DD(min)}$ ($V_{POR} < V_{DD} < V_{DD(min)}$)

When the voltage on V_{DD} is less than the device $V_{DD(min)}$ voltage, and greater than the power-on reset voltage (V_{POR}) , the \overline{RESET} signal is asserted and low impedance, respectively, regardless of the voltage on the SENSE pin.

8.4.3 Below Power-On Reset (V_{DD} < V_{POR})

When the voltage on V_{DD} is lower than the required voltage (V_{POR}) needed to internally pull the asserted output to GND, \overline{RESET} is undefined and should not be relied upon for proper device function.

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The following sections describe in detail how to properly use this device, depending on the requirements of the final application.

9.2 Typical Application

A typical application of the TPS3808G25 used with a 2.5-V processor is shown in Figure 9-1. The open-drain RESET output is typically connected to the RESET input of a microprocessor. A pullup resistor must be used to hold this line high when RESET is not asserted. The RESET output is undefined for voltage below 0.8 V, but this characteristic is normally not a problem because most microprocessors do not function below this voltage.

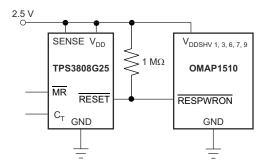


Figure 9-1. Typical Application of the TPS3808 With an OMAP Processor

9.2.1 Design Requirements

The TPS3808 is intended to drive the $\overline{\text{RESET}}$ input of a microprocessor. The $\overline{\text{RESET}}$ pin is pulled high with a 1-M Ω resistor and the reset delay time is controlled by C_T depending on the reset requirement times of the microprocessor. In this case, C_T is left open for a typical reset delay time of 20 ms.

9.2.2 Detailed Design Procedure

The primary constraint for this application is the reset delay time. In this case, because C_T is open, it is set to 20 ms. A 0.1- μ F decoupling capacitor is connected to the V_{DD} pin and a 1-M Ω resistor is used to pull up the RESET pin high. The \overline{MR} pin can be connected to an external signal if desired.

9.2.2.1 Immunity to SENSE Pin Voltage Transients

The TPS3808 is relatively immune to short negative transients on the SENSE pin. Sensitivity to transients depends on threshold overdrive. Threshold overdrive is defined by how much the V_{SENSE} exceeds the specified threshold, and is important to know because the smaller the overdrive, the slower the \overline{RESET} response. Threshold overdrive is calculated as a percent of the threshold in question, as shown in Equation 2:

Overdrive =
$$|(V_{SENSE} / V_{IT} - 1) \times 100\%|$$
 (2)

where:

V_{IT} is the threshold voltage.

Figure 9-2 shows this relationship.

9.2.3 Application Curve

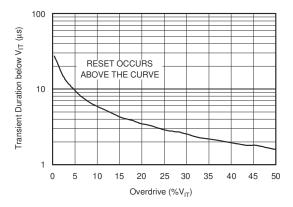


Figure 9-2. Maximum Transient Duration at SENSE vs SENSE Threshold Overdrive Voltage

10 Power Supply Recommendations

These devices are designed to operate from an input supply with a voltage range between 1.7 V and 6.5 V. Use a low-impedance power supply to eliminate inaccuracies caused by current changes during the voltage reference refresh.

11 Layout

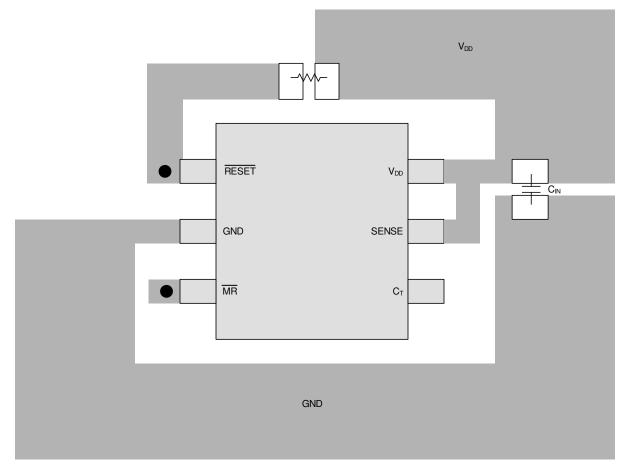
11.1 Layout Guidelines

Make sure the connection to the V_{DD} pin is low impedance. Place a 0.1- μ F ceramic capacitor near the V_{DD} pin. If no capacitor is connected to the C_T pin, parasitic capacitance on this pin should be minimized so the \overline{RESET} delay time is not adversely affected.

11.2 Layout Example

The layout example in Figure 11-1 shows how the TPS3808 is laid out on a printed circuit board (PCB) for a 20-ms delay.





Vias used to connect pins for application-specific connections

Figure 11-1. Layout Example for a 20-ms Delay

12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS3808. The TPS3808G01DBVEVM evaluation module (and related user guide) can be requested at the Texas Instruments website through the product folders or purchased directly from the TI eStore.

12.2 Documentation Support

12.2.1 Related Documentation

The following related documents are available for download at www.ti.com:

- Application note. Optimizing Resistor Dividers at a Comparator Input. Literature number SLVA450.
- Application note. Sensitivity Analysis for Power Supply Design. Literature number SLVA481.
- TPS3808G01DBVEVM Evaluation Module User Guide. Literature number SBVU015.

12.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossarv

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

Copyright © 2023 Texas Instruments Incorporated

www.ti.com

11-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS3808G01DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G01DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G01DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DRVR.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DRVR1G4	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DRVR1G4.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DRVRG4	Active	Production	WSON (DRV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G01DRVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DRVT.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G09DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G09DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G09DBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G09DBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G09DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G09DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G09DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G09DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G125DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC
TPS3808G125DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC
TPS3808G125DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC
TPS3808G125DBVRG4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC
TPS3808G125DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC
TPS3808G125DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC





www.ti.com 11-Nov-2025

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	(3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS3808G125DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G12DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	=	Call TI	Call TI	-40 to 125	
TPS3808G12DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	=	Call TI	Call TI	-40 to 125	
TPS3808G12DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVR.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVRG4	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVRG4.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVT.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVTG4	Active	Production	WSON (DRV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G15DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G15DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DBVT1G4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DBVT1G4.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G15DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DRVR.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DRVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DRVT.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G18DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	=	Call TI	Call TI	-40 to 125	





www.ti.com 11-Nov-2025

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS3808G18DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DBVT1G4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DBVT1G4.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G18DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DRVR.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DRVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DRVT.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G19DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G19DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G19DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G19DBVRG4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G19DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G19DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G25DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AVQ, EG25)
TPS3808G25DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AVQ, EG25)
TPS3808G25DBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G25DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G25DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DRVR.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DRVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DRVT.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G30DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVP





www.ti.com 11-Nov-2025

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS3808G30DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G30DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G30DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DRVR.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DRVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DRVT.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DRVTG4.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G33DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G33DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G33DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SEC
TPS3808G33DRVR.B	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SEC
TPS3808G33DRVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SEC
TPS3808G33DRVT.B	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SEC
TPS3808G50DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN
TPS3808G50DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN
TPS3808G50DBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN
TPS3808G50DBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN
TPS3808G50DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G50DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN
TPS3808G50DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN
TPS3808G50DBVTG4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	

⁽¹⁾ Status: For more details on status, see our product life cycle.

11-Nov-2025

www.ti.com

- (2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not vet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional
- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS3808:

Automotive : TPS3808-Q1

Enhanced Product: TPS3808-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



www.ti.com 16-Jul-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3808G01DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G01DBVR1G4	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G01DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G01DRVR	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G01DRVR1G4	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G01DRVT	WSON	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G01DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G09DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G09DBVR1G4	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G09DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G125DBVR	SOT-23	DBV	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G125DBVRG4	SOT-23	DBV	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G125DBVT	SOT-23	DBV	6	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G12DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G12DBVR1G4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G12DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3



PACKAGE MATERIALS INFORMATION

www.ti.com 16-Jul-2025

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter	Reel Width	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
					(mm)	W1 (mm)	` ′	` ′	<u> </u>	` ,		
TPS3808G12DRVR	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G12DRVRG4	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G12DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G12DRVT	WSON	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G15DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G15DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G15DBVT1G4	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G15DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G15DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G18DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G18DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G18DBVT1G4	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G18DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G19DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G19DBVRG4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G19DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G25DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G25DBVR1G4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G25DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G25DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G25DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G30DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G30DBVR1G4	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G30DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G30DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G30DRVR	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G30DRVT	WSON	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G30DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G33DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G33DBVR1G4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G33DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G33DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G33DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G50DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G50DBVR1G4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G50DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3



www.ti.com 16-Jul-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3808G01DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G01DBVR1G4	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G01DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G01DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS3808G01DRVR1G4	WSON	DRV	6	3000	205.0	200.0	33.0
TPS3808G01DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS3808G01DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS3808G09DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G09DBVR1G4	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G09DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G125DBVR	SOT-23	DBV	6	3000	200.0	183.0	25.0
TPS3808G125DBVRG4	SOT-23	DBV	6	3000	200.0	183.0	25.0
TPS3808G125DBVT	SOT-23	DBV	6	250	200.0	183.0	25.0
TPS3808G12DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G12DBVR1G4	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G12DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G12DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS3808G12DRVRG4	WSON	DRV	6	3000	205.0	200.0	33.0



PACKAGE MATERIALS INFORMATION

www.ti.com 16-Jul-2025

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3808G12DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS3808G12DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS3808G15DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G15DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G15DBVT1G4	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G15DRVR	WSON	DRV	6	3000	200.0	183.0	25.0
TPS3808G15DRVT	WSON	DRV	6	250	200.0	183.0	25.0
TPS3808G18DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G18DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G18DBVT1G4	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G18DRVT	WSON	DRV	6	250	200.0	183.0	25.0
TPS3808G19DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G19DBVRG4	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G19DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G25DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G25DBVR1G4	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G25DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G25DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS3808G25DRVT	WSON	DRV	6	250	200.0	183.0	25.0
TPS3808G30DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G30DBVR1G4	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G30DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G30DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS3808G30DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS3808G30DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS3808G30DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS3808G33DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G33DBVR1G4	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G33DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G33DRVR	WSON	DRV	6	3000	200.0	183.0	25.0
TPS3808G33DRVT	WSON	DRV	6	250	200.0	183.0	25.0
TPS3808G50DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G50DBVR1G4	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G50DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4206925/F







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.





NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature
- number SLUA271 (www.ti.com/lit/slua271).

 5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.





NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.





NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.





NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025